NSN 5961-00-350-2215

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-350-2215 **Inclosure Material:** Metal **Overall Length:** 0.290 inches **Terminal Length:** 0.070 inches **Overall Height:** 0.035 inches **Overall Width:** 0.150 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 10.0 collector-to-base voltage, instantaneous all transistor **Current Rating Per Characteristic:** 1.00 milliamperes repetitive peak forward current megahertz all transistor **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 10 pin **Specification Data:** 80131-release5004 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0